

■ Features

- Low Conduction and Switching Loss
- Positive Temperature Coefficient on V_f
- Temperature Independent Switching Behavior
- Fast Reverse Recovery
- High Surge Current Capability
- Pb-free lead plating

■ Benefits

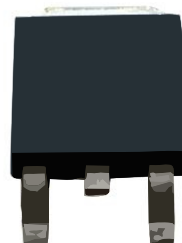
- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

■ Applications

- SMPS
- PFC
- Solar/Wind Renewable Energy
- Power Inverters
- Motor Drives

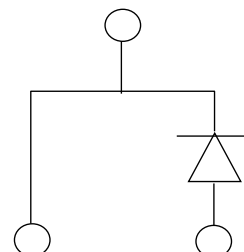
■ Maximum ratings and electrical characteristics

■ Outline



1 2

Package TO-252-2L



1 2

Inner Circuit

Parameter	Conditions	Symbol	SICD03C60			UNIT
Marking code			SICD03C60			
Peak Repetitive Reverse Voltage	T _J =25°C	V _{RRM}	600			V
Peak Reverse Surge Voltage	T _J =25°C	V _{RSM}	600			
DC Blocking Voltage	T _J =25°C	V _R	600			
Continuous Forward Current	T _c =25°C	I _F	7			A
	T _c =135°C		3			
	T _c =157°C		2			
Non-Repetitive Peak Forward surge current	T _c =25°C, T _p =10ms, Half Sine-Wave	I _{FSM}	18			A
	T _c =125°C, T _p =10ms, Half Sine-Wave		15			
	T _c =25°C, T _p =10us, Pulse		92			
Repetitive Peak Forward surge current	T _c =25°C, T _p =10ms, Half Sine-Wave, D=0.1	I _{FRM}	14			A
	T _c =125°C, T _p =10ms, Half Sine-Wave, D=0.1		13			
Power Dissipation	T _c =25°C	P _D	30			W
	T _c =125°C		10			
Operation Junction and Storage Temperature		T _J	175			°C
		T _{stg}	-55 to 175			
Thermal Resistance Junction to Case		R _{θJC}	5			°C/W
Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
DC Blocking Voltage	I _R =100uA, T _J =25°C	V _{DC}		>650		V
Forward Voltage	I _F =2A, T _J =25°C	V _F		1.5	1.8	V
	I _F =2A, T _J =175°C			1.9	2.2	
Reverse Current	V _R =600V, T _J =25°C	I _R		<1	30	uA
	V _R =600V, T _J =125°C			2	80	
Total Capacitive Charge	I _F =2A, dI/dt=300A/us, V _R =400V, T _J =25°C	Q _C		7		nC
Total Capacitive	V _R =1V, T _J =25°C, f=1MHz	C		85		pF
	V _R =200V, T _J =25°C, f=1MHz			15		
	V _R =400V, T _J =25°C, f=1MHz			15		

■ Rating and characteristic curves

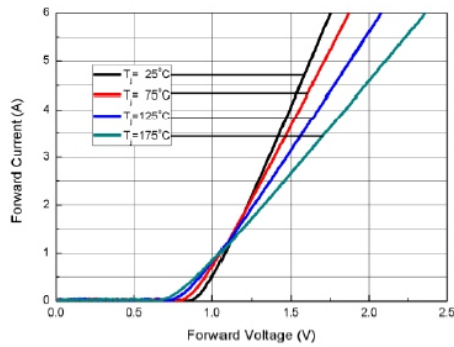


Fig. 1 Forward Characteristics

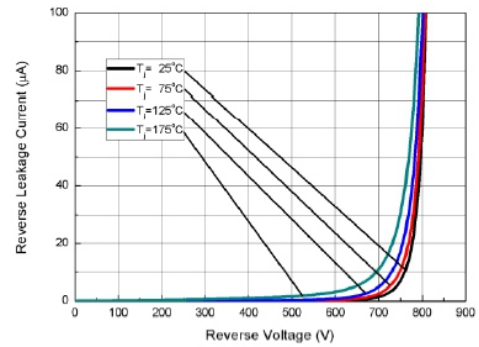


Fig. 2 Reverse Characteristics

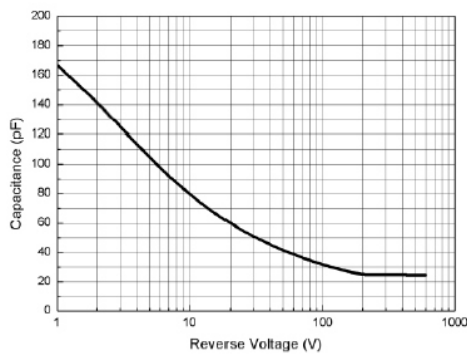


Fig. 3 Capacitance vs. Reverse Voltage

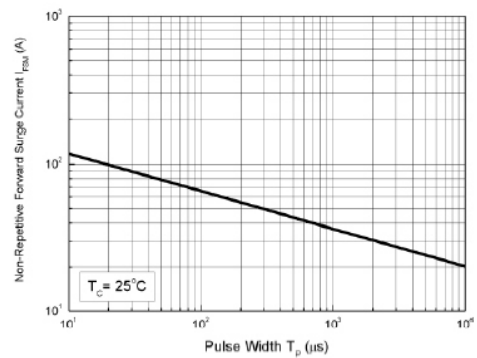


Fig. 4 Non-Repetitive Peak Forward Surge Current (Pulse Mode)

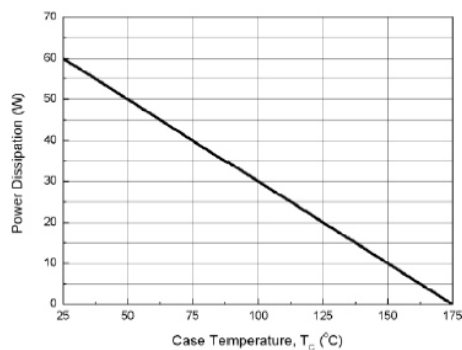


Fig. 5 Power Derating

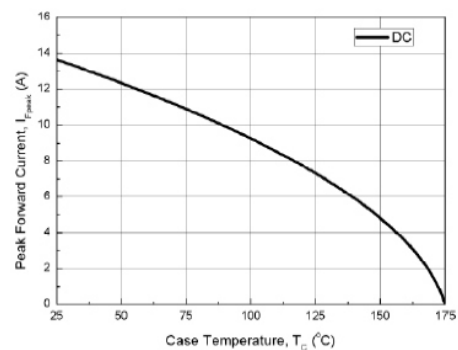
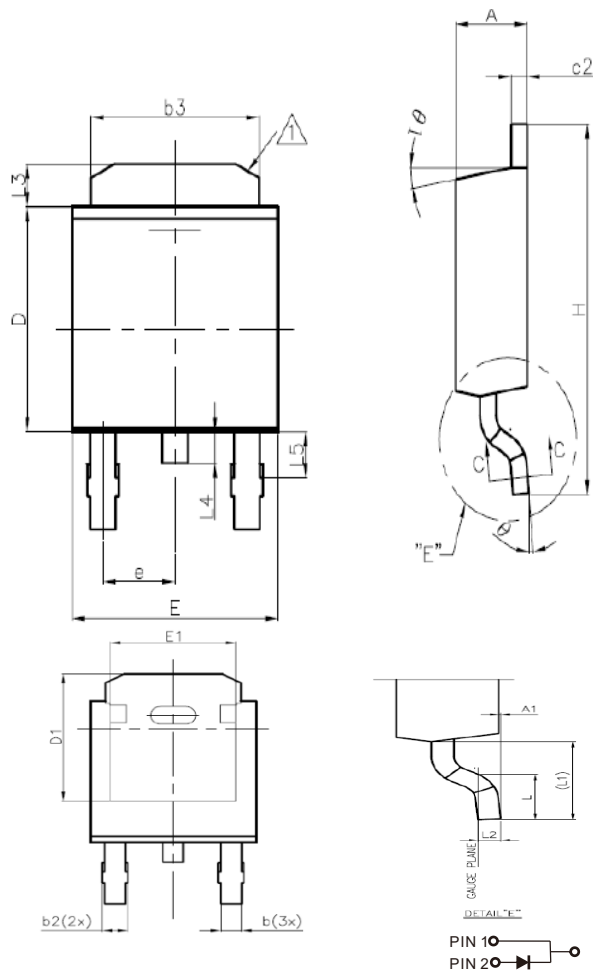


Fig. 6 Current Derating

■ Outline

TO-252-2L



symbol	Dimensions in inches(millimeters)		
	Min	Nom	Max
A	0.086	0.090	0.094
A1	0.00	—	0.005
b	0.025	—	0.035
b1	0.028	0.032	0.036
b2	0.028	—	0.045
b3	0.205	—	0.215
c	0.018	—	0.023
c1	0.016	0.020	0.022
c2	0.018	—	0.023
D	0.235	0.240	0.245
D1	0.205	—	—
E	0.250	0.257	0.265
E1	0.170	—	—
e	—	0.090	—
H	0.370	0.390	0.410
L	0.055	0.060	0.065
L	0.539(13.7)	—	0.555(14.10)
L1	—	0.104	—
L2	—	0.020	—
L3	0.035	0.046	0.050
L4	0.025	0.033	0.040
L5	0.045	0.049	0.060
Ø	0	—	10
Ø1	0	—	15

NOTES:

- 1.All dimension are in mm[inch].
- 2.Tolerance:±0.004inch.

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